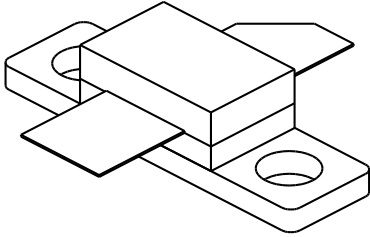


0912-45

45 Watts, 50 Volts, Pulsed
Avionics 960 - 1215 MHz

<p>GENERAL DESCRIPTION The 0912-45 is a COMMON BASE bipolar transistor. It is designed for pulsed systems in the frequency band 960-1215 MHz. The device has gold thin-film metallization for proven highest MTTF. The transistor includes input prematch for broadband capacity. Low thermal resistance package reduces junction temperature, extends life.</p>	<p>CASE OUTLINE 55CX, STYLE 1</p> 
<p>ABSOLUTE MAXIMUM RATINGS Maximum Power Dissipation @ 25°C² 225 Watts</p> <p>Maximum Voltage and Current BVces Collector to Base Voltage 60 Volts BVebo Emitter to Base Voltage 4.0 Volts Ic Collector Current 4.5 Amps</p> <p>Maximum Temperatures Storage Temperature - 65 to + 150°C Operating Junction Temperature + 200°C</p>	

ELECTRICAL CHARACTERISTICS @ 25 °C

SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
P_{out}	Power Out	F = 960-1215 MHz	45			Watts
P_{in}	Power Input	V _{cc} = 50 Volts			7.0	Watts
P_{g2}²	Power Gain	PW = 10 μsec	8.0	9.0		dB
η_c	Collector Efficiency	DF = 1%		45		%
VSWR²	Load Mismatch Tolerance	F = 1090 MHz			10:1	

BVebo	Emitter to Base Breakdown	I _e = 25 mA	4.0			Volts
BVces	Collector to Emitter Breakdown	I _c = 75 mA	60			Volts
Cob	Capacitance Collector to Base	V _{cb} = 50V		20		pF
h_{FE}	DC - Current Gain	I _c = 300 mA, V _{ce} = 5 V	10			
θ_{jc}²	Thermal Resistance				0.8	°C/W

Note 1: At rated output power and pulse conditions
2: At rated pulse conditions

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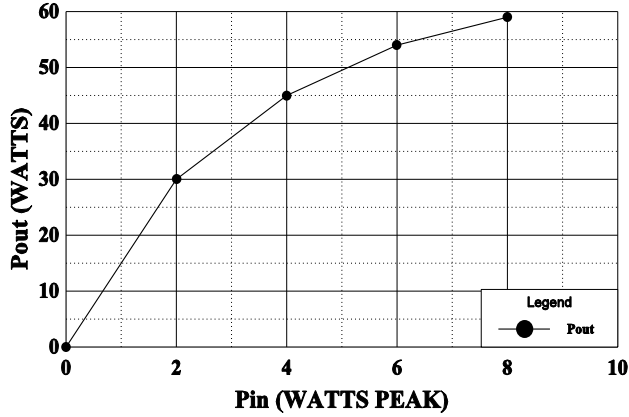


GHz TECHNOLOGY
RF-MICROWAVE SILICON POWER TRANSISTORS

0912-45

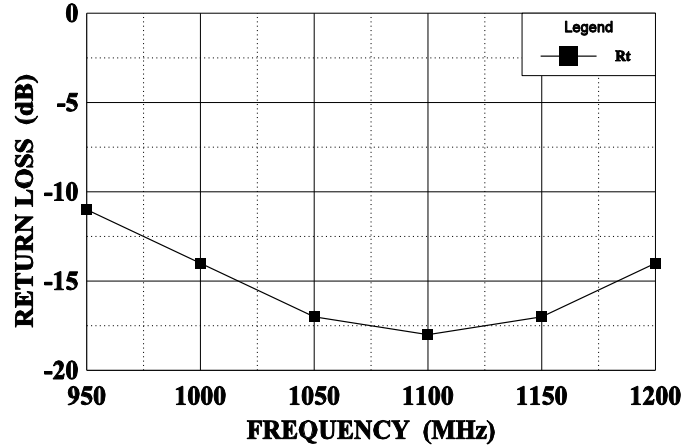
POWER OUTPUT vs POWER INPUT

Vcc = 50 V, F = 1090 MHz



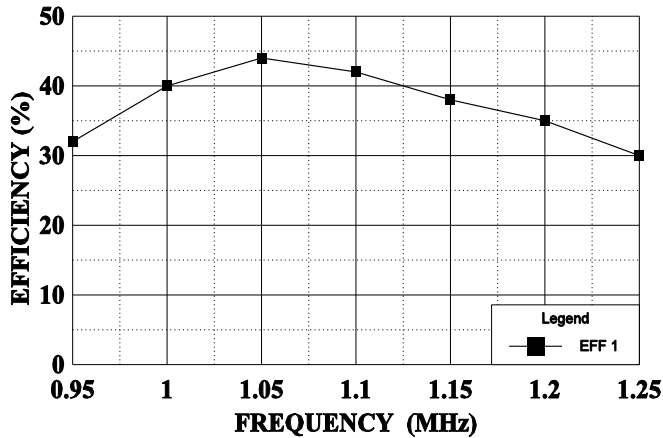
WIDEBAND CIRCUIT INPUT RETURN LOSS

Vcc = 50 V, Pin = 7.0 W



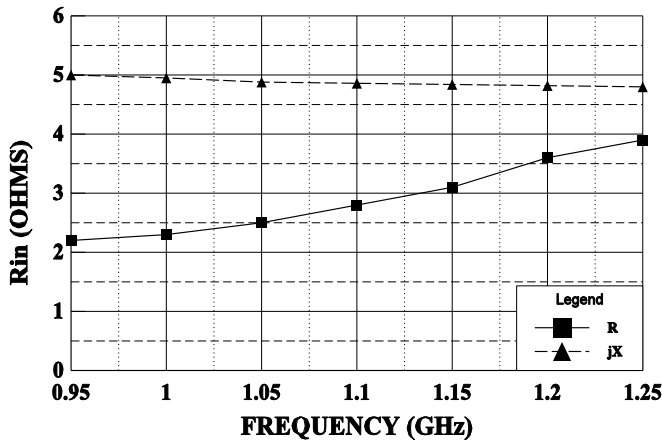
EFFICIENCY vs FREQUENCY

Vcc = 50 V, Pin = 7.0 W



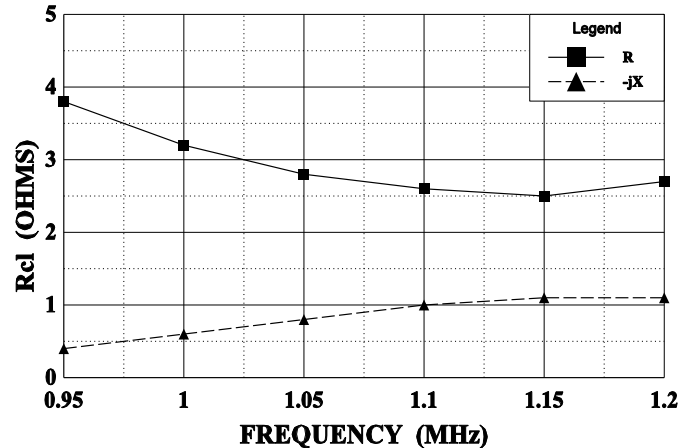
SERIES INPUT IMPEDANCE vs FREQUENCY

Vcc = 50 V, Pin = 7.0 W

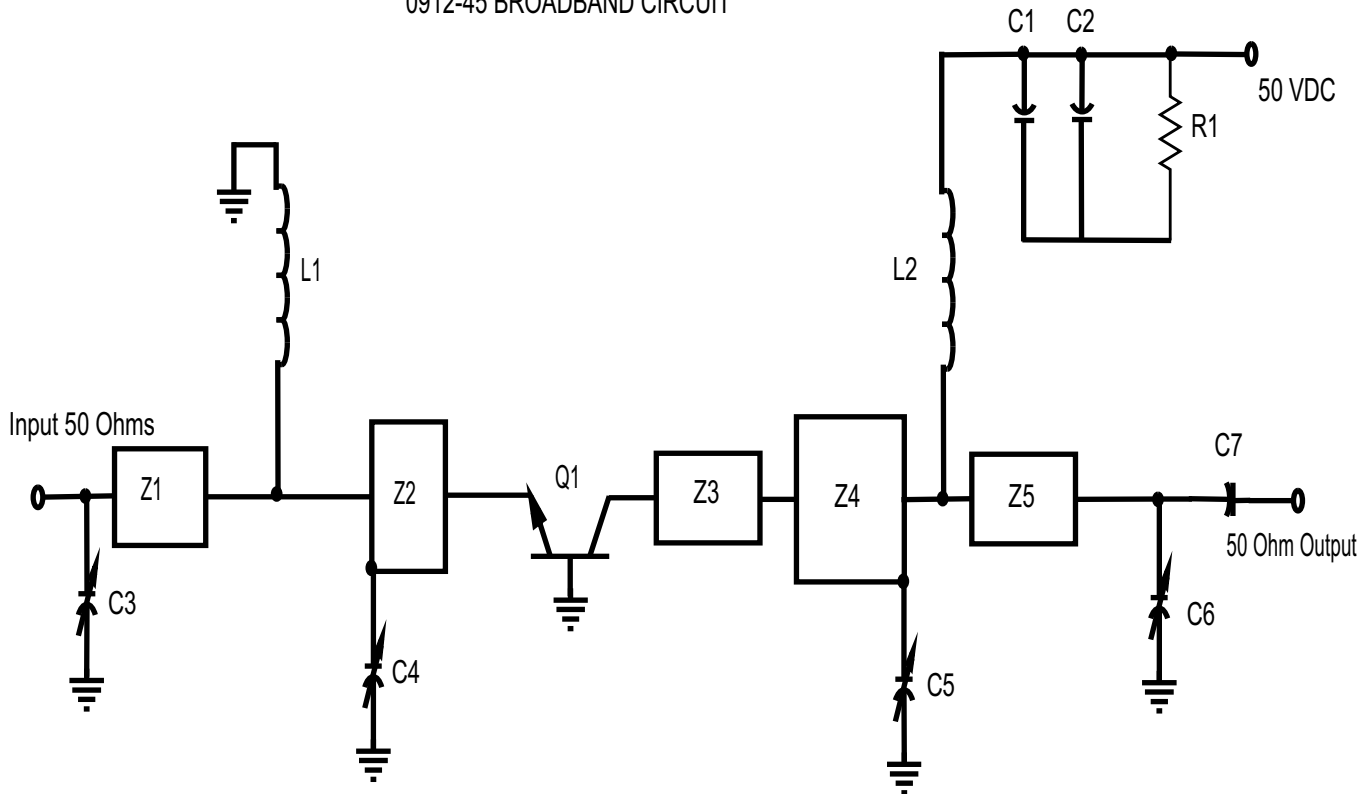


SERIES LOAD IMPEDANCE vs FREQUENCY

Vcc = 50 V, Pin = 7.0 W



0912-45 BROADBAND CIRCUIT



PC Board Material .010" Dielectric Teflon Fiberglass

Z1=50 , .08 , = .027"w X .59"L
 Z2=2.7 .064 , = .80"w X .44"L
 Z3=10 , .062 , = .20"w X .443"L
 Z4=3.7 , .08 , = .55"w X .55"L
 Z5=50 , .075 , = .027"w X .56"L
 L1= Inductor #14 wire, 0.7" long
 L2= Inductor #18 wire, 1.5" long

C1=Capacitor 100 pF "B" (100mil) ATC
 C2=Capacitor 68mfd, 75V Electrolytic
 C3, C4, C5, C6= Capacitor .35-3.5pF Piston Trimmer
 C4=Capacitor 47pF "B" (100mil) ATC
 R1= Resistor, 15WK 1/4W
 Q1=GHz Transistor 0912-45

All electrical lengths taken at 1.09 GHz